

DATASHEET

4 PIN SOP PHOTOTRANSISTOR PHOTOCOUPLER EL357N-G Series



2 3

Schematic

Features:

- Current transfer ratio (CTR: $50\sim600\%$ at $I_F = 5mA$, $V_{CE} = 5V$)
- High isolation voltage between input and output (Viso=3750 V rms)
- Compact 4 Pin SOP with a 2.0 mm profile
- Compliance with EU REACH
- Pb free and RoHS compliant
- UL and cUL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

Description

The EL357N-G series contains an infrared emitting diode, optically coupled to a phototransistor detector.

The devices in a 4-pin small outline SMD package.

Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances



Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	50	mA
Input	Peak forward current (1us, pulse)	I _{FP}	1	А
	Reverse voltage	V _R	6	V
	Power dissipation	Б	70	mW
	Derating factor (about Ta=100°C)	P_{D}	2.9	mW/C
	Power dissipation	_	150	mW
Output	Derating factor (above $T_a = 70^{\circ}C$)	P _C	3.7	mW/°C
	Collector current	I _C	50	mA
	Collector-Emitter voltage	V _{CEO}	80	V
	Emitter-Collector voltage	V _{ECO}	7	V
Total Power Dissipation		P _{TOT}	200	mVV
Isolation '	Voltage*1	V _{ISO}	3750	V rms
Operating	temperature	T _{OPR}	-55 ~ +110	°C
Storage to	emperature	T _{STG}	-55 ~ +125	°C
Soldering	Temperature*2	T _{SOL}	260	°C

Notes:

 $^{^*1}$ AC for 1 minute, R.H.= $40 \sim 60\%$ R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

^{*2} For 10 seconds



Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V_{F}	-	1.2	1.4	V	$I_F = 20 \text{mA}$
Reverse current	I_R	-	-	10	μΑ	$V_R = 4V$
Input capacitance	C _{in}	-	30	250	pF	V = 0, f = 1kHz

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter dark current	I _{CEO}	-	-	100	nA	$V_{CE} = 20V$, $I_F = 0mA$
Collector-Emitter breakdown voltage	BV_CEO	80	-	-	V	$I_C = 0.1 \text{mA}$
Emitter-Collector breakdown voltage	BV _{ECO}	7	-	-	V	I _E = 0.01mA

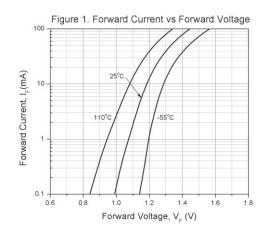
Transfer Characteristics (T_a=25°C unless specified otherwise)

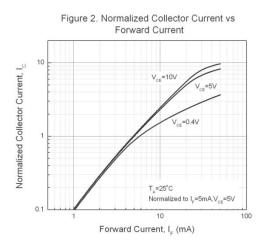
Transier C	Characteristic	55 (Ta=25 C	uniess sp	ecinea c	illerwise)			
Parameter		Symbol	Min	Тур.	Max.	Unit	Condition	
	EL357N		50	- 1	600			
	EL357NA	CTR	80	-	160			
Current	EL357NB		130		260		$I_F = 5mA$, $V_{CE} = 5V$	
Transfer	EL357NC		200	-	400			
ratio	EL357ND		300	-	600			
	EL357NE		100	-	200			
	EL357NF		150	-	300			
	Collector-Emitter saturation voltage		-	0.1	0.2	V	$I_F = 20 \text{mA}$, $I_C = 1 \text{mA}$	
Isolation resistance		R _{IO}	5×10 ¹⁰	-	-	Ω	V _{IO} = 500Vdc, 40~60% R.H.	
Floating ca	Floating capacitance		-	0.6	1.0	pF	$V_{IO} = 0$, $f = 1MHz$	
Rise time	Rise time		-	3	18	- 110	$V_{CE} = 2V, I_{C} = 2mA,$	
Fall time		t _f	-	4	18	- µs	$R_L = 100\Omega$	

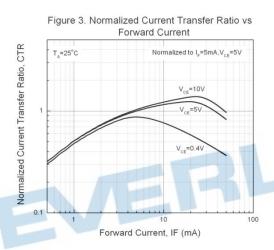
^{*} Typical values at T_a = 25°C

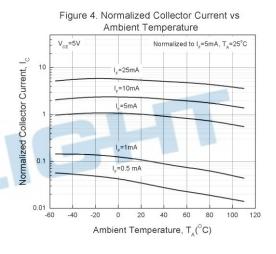


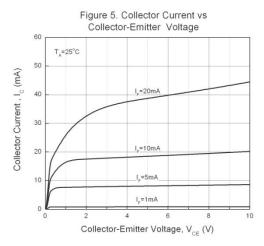
Typical Electro-Optical Characteristics Curves

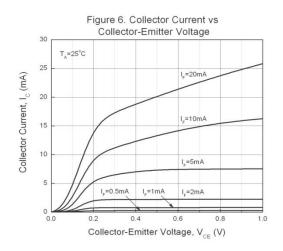














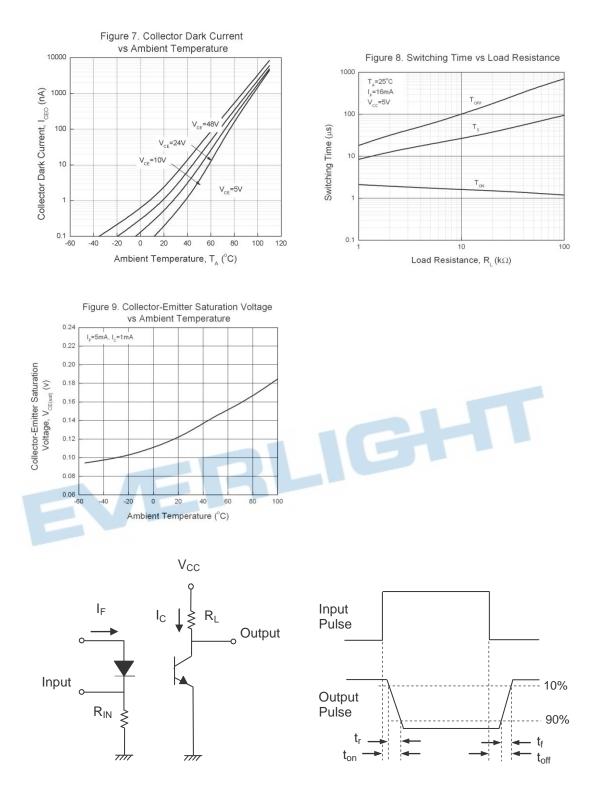


Figure 10. Switching Time Test Circuit & Waveforms



Order Information

Part Number

EL357N(X)(Y)-VG

Note

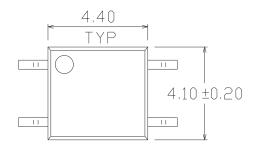
X = CTR Rank (A, B, C, D, E, For none) Y = Tape and reel option (TA, TB or none).

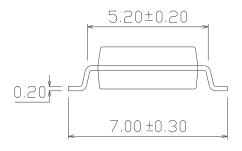
V = VDE (option) G = Halogen free

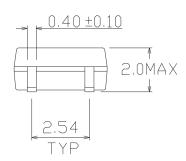
Option	Description	Packing quantity				
None	Standard SMD option	100 units per tube				
-V	Standard SMD option + VDE	100 units per tube				
(TA)	TA Tape & reel option	3000 units per reel				
(TB)	TB Tape & reel option	3000 units per reel				
(TA)-V	TA Tape & reel option + VDE	3000 units per reel				
(TB)-V	TB Tape & reel option + VDE	3000 units per reel				
(1B)-V Tape & reel option + VBL						



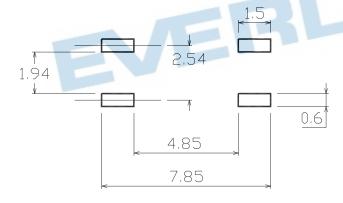
Package Dimension (Dimensions in mm)







Recommended pad layout for surface mount leadform





Device Marking



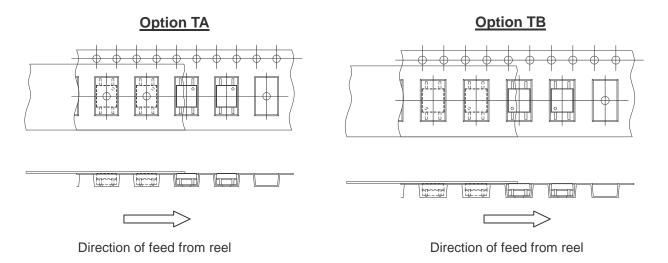
Notes

EL denotes Everlight
357N denotes Device Number
R denotes CTR Rank
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE approved (optional)

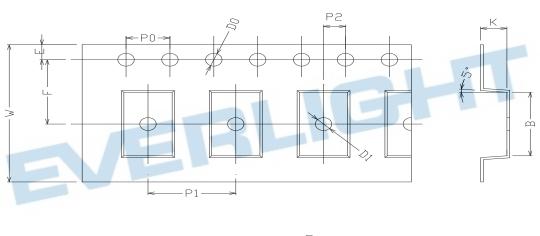




Tape & Reel Packing Specifications



Tape dimensions





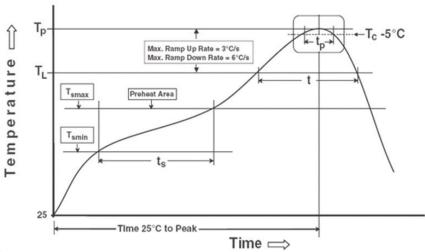
Dimension No.	Α	В	Do	D1	E	F
Dimension (mm)	4.4 ± 0.1	7.4 ± 0.1	1.5 + 0.1/-0	1.5 ± 0.1	1.75± 0.1	7.5 ± 0.05
Dimension No.	Ро	P1	P2	t	W	К
Billionolon 140.				·		



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

Temperature min (T_{smin})

Temperature max (T_{smax})

Time $(T_{smin} \text{ to } T_{smax}) (t_s)$

Average ramp-up rate (T_{smax} to T_p)

Other

Liquidus Temperature (T_L)

Time above Liquidus Temperature (t L)

Peak Temperature (T_P)

Time within 5 °C of Actual Peak Temperature: T_P - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C

200°C

60-120 seconds

3 °C/second max

217 °C

60-100 sec

260°C

30 s

6°C /second max.

8 minutes max.

3 times



DISCLAIMER

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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